Valve Electronic

GENERAL POST OFFICE: (R.S.)

(SEMICONDUCTOR)

CV 5276

Specification: GFO/CV 5276 Issue 1. Dated October 1960	Security			
To be read in conjunction with K1007 Mandatory Sections. 1, 2, 3, 4, 5. 1,5. 2,5. 3,6,9,15. Other sections and Appendices as called up by this	Specification	<u>Valve</u>		
specification.	Unclassified	Unclassified		

Type of Valve: Silicon Junction Zener No	Marking			
Prototype: KS15	See K1007/4. The positive lead should be marked red.			
RATINGS and CHARACTERISTICS (Not for Inspection purposes All limiting values are absolu	<u>Dimensions</u> See K1007/A1/D6			
Max. mean dissipation at 55°C ambient air (mW) Power derating above 75°C	150	A		
Max. reference voltage at 1 mA, at 25°C ambient air (V) Min. reference Voltage at 1 mA, at 25°C ambient air (V) Max. slope resistance at 1 mA, at 25°C ambient air (N) Max. peak reference current at 25°C ambient air (MA)	7.9 7.1 50 40		EODY The body shall be insulated from all leads or alternatively, shall be covered with an approved insulating sleeve. MOUNTING FOSITION Any.	
Notes A. Averaged over any 20 m Sec period B. Joint Service Catalogue Number 5960-	99-037-	2316	<u>Packaging</u> K1007/14	

CV 5276 To be performed in addition to those applicable in K 1007

K 1007	Test	Test Conditions	ACL	Insp.		Limits		Truck	
,			1 %	Level		Min.	Max.	Unita	
	GROUP A								
	Zener voltage		Ir d.c. = 1.0 mA		100%	v z	7.1	7.9	v
	Noise Voltage (rms)	(1)	Ir d.c. = 1.0 mA Centre frequency = 16 kc/s Note 3		100%	Vn 1	1.5	-	'nΛ
	Noise Voltage (rms)	(2)	d.c. conditions as for Noise Test 1. Centre frequency = 200 c.p.s. Note 3		100%	Vn 2	-	√2Vn1	Æ
	Noise Voltage (rms)	(3)	Ir varied between 0.5 to 1.0 mA d.c. Centre frequency = 16 kc/s Note 3		100%	Vn 3	1.5	5.0	JuV
	Incremental Impedance		d.c. conditions Ir is varied between 0.5 to 1.0 mA. A 1 mV rms a.c. Signal f = 1 kc/s is applied from a source impedance of 600 \(\oldsymbol{\alpha} \)		100%	Z	-	50	C
***************************************	GROUP B Omitted		-						
	GROUP C T amb = -10 ± Noise Voltage (rms)			2.5	1	Vn 1	1.3	-	μV
	GROUP D Omitted								

Page 3

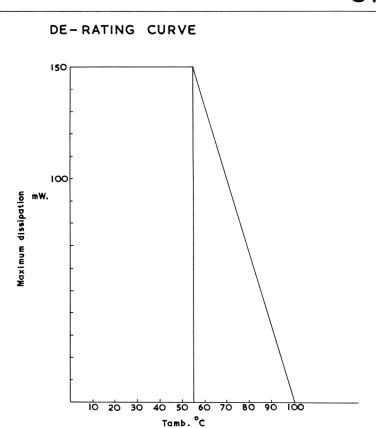
CV 5276

K 1007	Test	Test Conditions	ACL %	Insp. Level	Sym.	Li	Limits	
					-	Min.	Max.	Units
	GROUP E							
10.2	Temperature cycling	Three cycles -55°C to +100°C No voltages		1C				
10.3	Climatic cycling	No voltages Note 1						
	Post Temperature and Climatic cycling tests							
8	Inoperatives	No voltages						
	Noise Voltage (1)	As in Group A	6.5		Vn 1	1.3	-	μV
	Noise Voltage (2)	As in Group A	6.5		V n 2	-	J2Vn1	μV
	Noise Voltage (3)	As in Group A	6.5		Vn 3	1.3	6.0	μV
	Incremental Impedance	As in Group A	6.5		Z	-	55	Ω
11.3	Fatigue	No voltages		1C				
	Post Fatigue tests	Combined ACL	10					
8	Inoperatives	No voltages	6.5					
	Noise Voltage (1)	As in Group A	6.5		Vn 1	1.3	-	μV
11.4	Shock	No Voltages Hammer angle = 60		т.А.				
	Post Shock tests	Combined ACL	10					
8	Inoperatives	No Voltages	6.5					
	Noise Voltages (1)	As in Group A	6.5		Vn 1	1.3	- ,	μV
10.1	Lead Fragility	No Voltages Note 2	6.5	1C				
11.5	Soldering	No Voltages	6.5	1C				
		L					V 5276	L

CV 5276/1/3

CV 5276

K 1007	Test	Test Conditions	AGL %	Insp. Level		Limits		Units
						Min.	t .	
13	GROUP F	PC = 150 mW T amb.=55°C With diode passing reverse d.c. current. Note 4.		1&				
13.3	Life Test End Point 1000 hours	Combined ACL	10		*			
	Zener Voltage	As in Group A	6.5		٧z	6.9	8.1	v
	Noise Voltage (1) (rms)	As in Group A	6.5		Vn 1	1.3	-	μV
	Noise Voltage (2) (rms)	As in Group A	6.5		Vn 2	-	J2V n1	μV
	Noise Voltage (3)	As in Group A	6.5		Vn 1	1.3	6.0	μV
	Incremental Impedance	As in Group A	6.5			-	55	Ω
8	Inoperatives	No voltages	6.5					
13.4	Storage Life (1)	t = 150 hours T = -55°C		1				
13.5	Storage Life (2)	t = 150 hours T = +100°C		1				
	Post Storage Life Tests							
	Repeat Group A Tests	Combined AQL for Storage Life (1)	2.5					
		Combined AGL for Storage Life (2)	4.0	•				
	GROUP G							
5.2.2.11	Re-test after 28 days holding period			100%				
8	Inoperatives	No voltages	0.5					
	Noise Voltage (1)	As in Group A	2.0		Vn 1	1.5	-	μV



NOTES

- The sample of diodes shall be subjected to conditioning in accordance with K1007, Section 10.1 shall then be subjected to climatic cycling and shall then pass the post climatic cycling tests.
- Diodes used for this test must have undergone at least 28 cycles of the climatic test in accordance with K1007. Section 10.3.1 or 10.3.2 or 6 cycles in accordance with Section 10.3.3.
- 3. The maximum and minimum limits given relate to a bandwidth of 220 cps; $\sqrt{\frac{\Delta f}{200}}$ for any other bandwidth Δf cps, the limits should be multiplied by
- 4. Alternatively the life test may be carried out at any ambient temperature between 55°C and 90°C at a dissipation shown on the de-rating curve corresponding to the chosen ambient temperature.